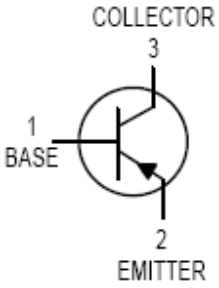
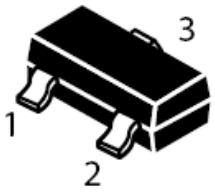
LITE-ON SEMICONDUCTORS

BC858

PNP General Purpose Transistor





FEATURES

- Ideally suited for automatic insertion
- For Switching and AF Amplifier Applications

MECHANICAL DATA

- Case: SOT-23 Plastic
- Case material: “Green” molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)
- Lead Free in RoHS 2002/95/EC Compliant

Maximum Ratings @ T_A = 25℃

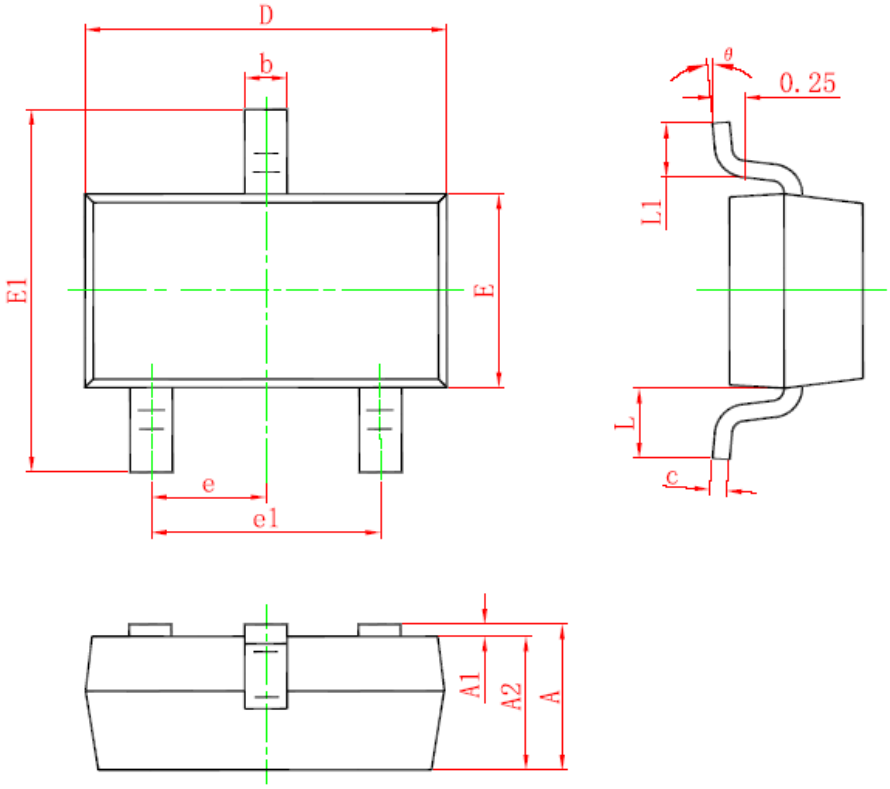
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-30	V
Collector-Emitter Voltage	V_{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current -Continuous	I_C	-100	mA
Collector Power Dissipation	P_C	200	mW
Junction Temperature	T_J	150	℃
Storage Temperature Range	T_{STG}	-65~+150	℃

Electrical Characteristics @ T_A = 25℃ unless otherwise specified

Characteristic	Test Condition	Symbol	Min.	Typ.	Max.	Unit
Collector-base breakdown voltage	I_C=-10μA,I_E=0	V_{CBO}	-30			V
Collector-emitter breakdown voltage	I_C=-10mA,I_B=0	V_{CEO}	-30			V
Emitter-base breakdown voltage	I_E=-1μA,I_C=0	V_{EBO}	-5			V
Collector-base cut-off current	V_{CB}=-25V,I_E=0	I_{CBO}			-0.1	uA
Collector-emitter cut-off current	V_{CB}=-25V,I_B=0	I_{CEO}			-0.1	uA
Emitter-base cut-off current	V_{CB}=-5V,I_C=0	I_{EBO}			-0.1	uA
DC current gain	V_{CE}=-5V,I_C=-2mA A B C	h_{FE}	125 220 420		250 475 800	
Collector-emitter saturation voltage	I_C=-100mA,I_B=-5mA	V_{CE}(sat)			-0.5	V
Base-emitter saturation voltage	I_C=-100mA,I_B=-5mA	V_{BE}(sat)			-1.1	V
Transition frequency	V_{CE}=-5V,I_C=-10mA, f=100MHz	f_T	100			MHz
Collector output capacitance	V_{CB}=-10V,f=1MHz	C_{ob}			4.5	pF

REV. 2, Jun-2012, KSPR09

SOT-23 Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	6°

Device Marking :

Device P/N	Classification of h_{FE}	Marking code
BC858A	125-250	3J
BC858B	220-475	3K
BC858C	420-800	3L

Electrical characteristic curves

Fig.1 DC Current Gain vs. Collector Current_BC858A

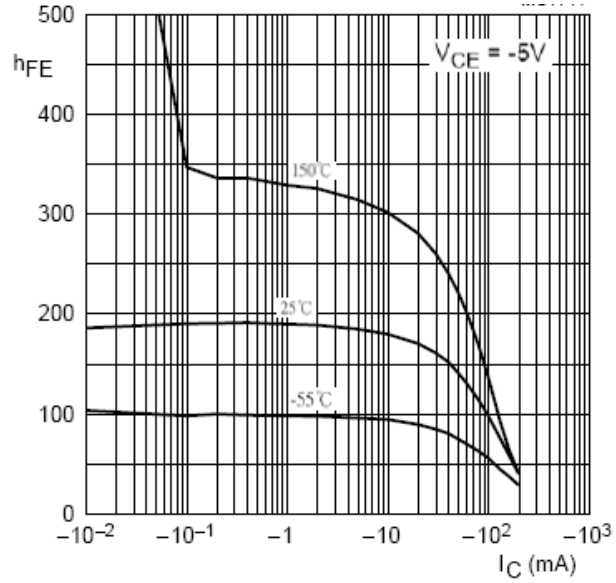


Fig.2 Grounded Emitter Propogation_BC858A

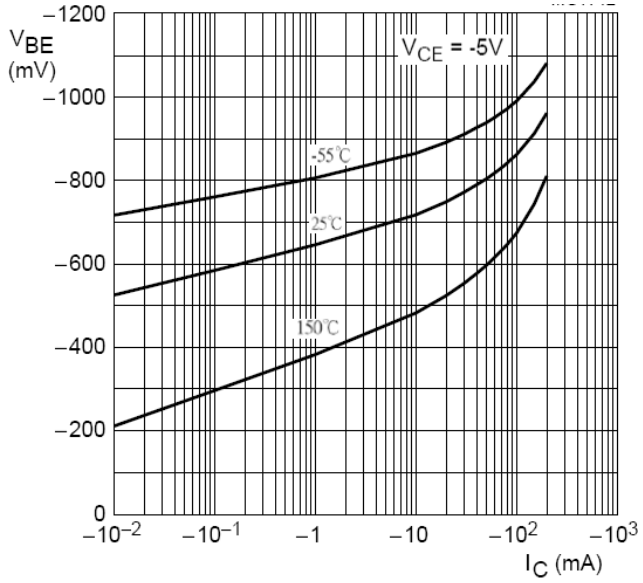


Fig.3 Collector Emitter Saturation Voltage vs. Collector Current_BC858A

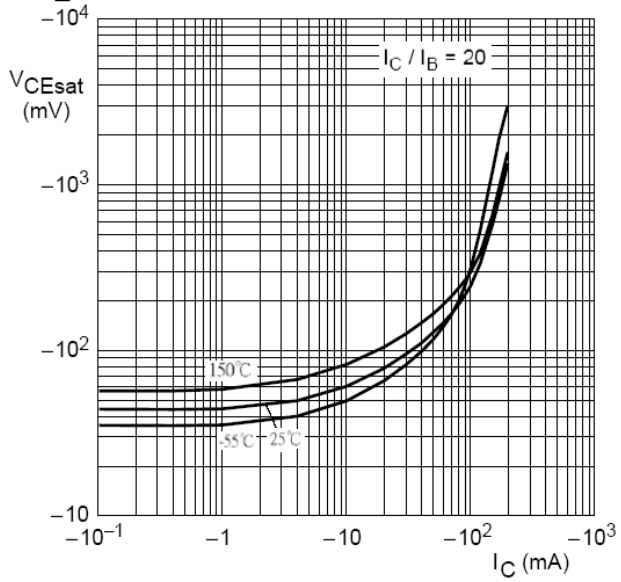


Fig.4 Base Emitter Saturation Voltage vs. Collector Current_BC858A

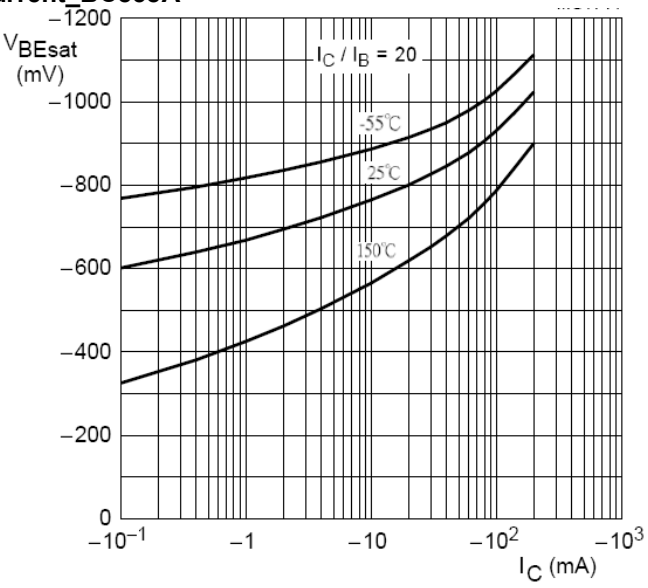


Fig.5 DC Current Gain vs. Collector Current_BC858B

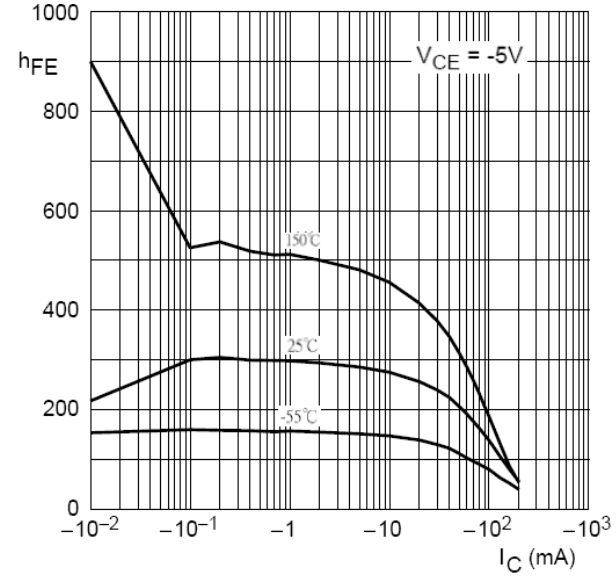


Fig.6 Grounded Emitter Propogation_BC858B

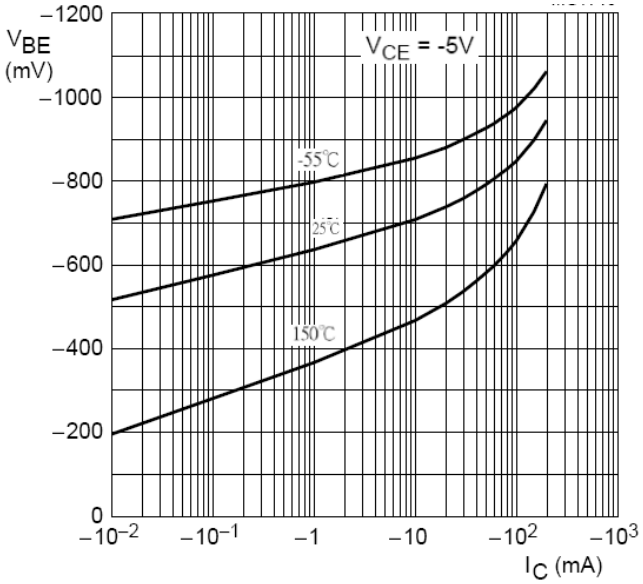


Fig.7 Collector Emitter Saturation Voltage vs. Collector Current_BC858B

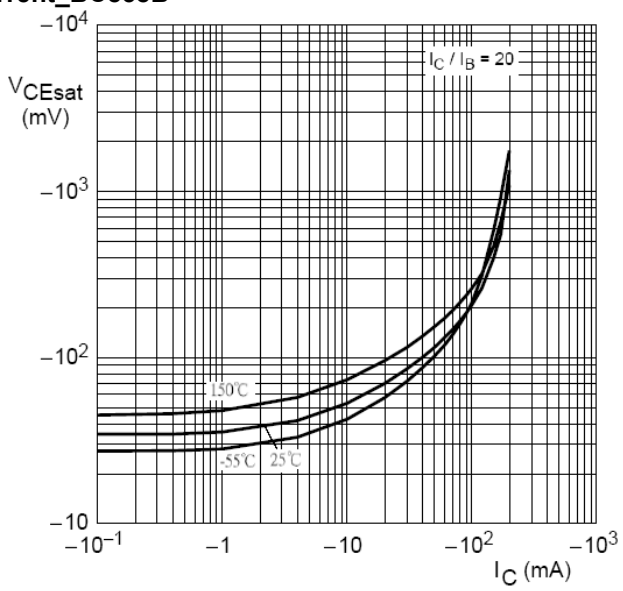


Fig.8 Base Emitter Saturation Voltage vs. Collector Current_BC858B

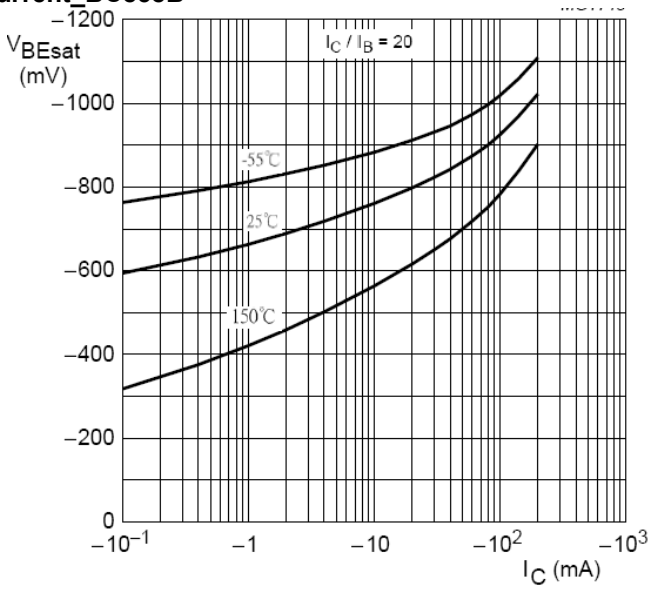


Fig.9 DC Current Gain vs. Collector Current_BC858C

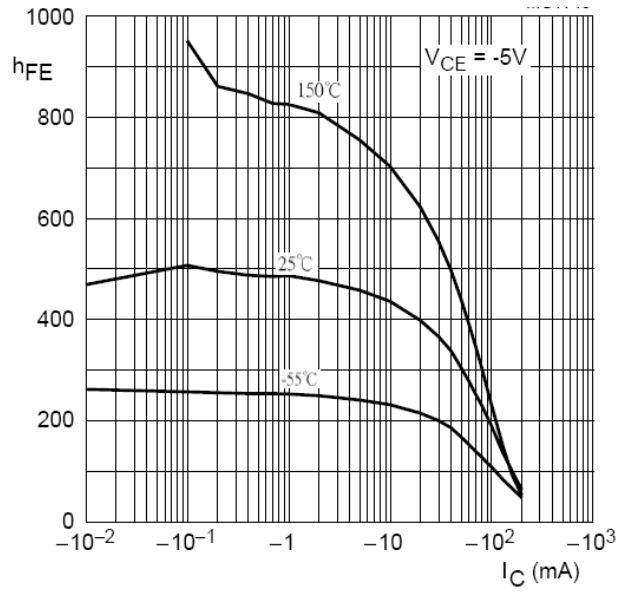


Fig.10 Grounded Emitter Propogation_BC858C

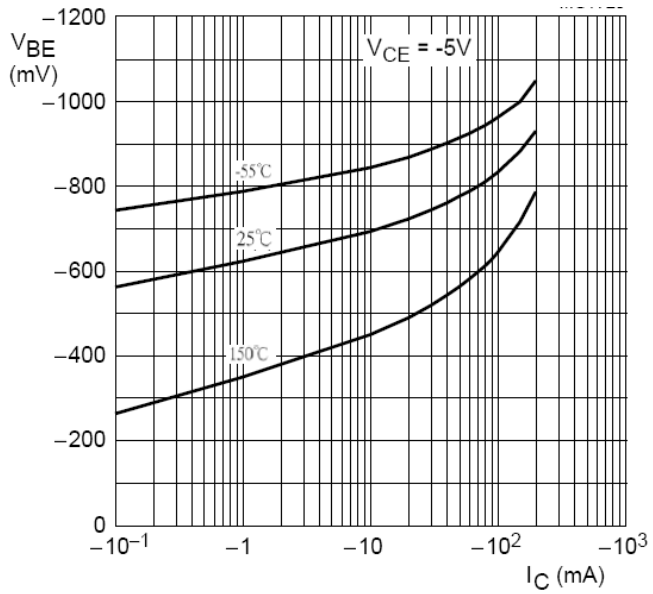


Fig.11 Collector Emitter Saturation Voltage vs. Collector Current_BC858C

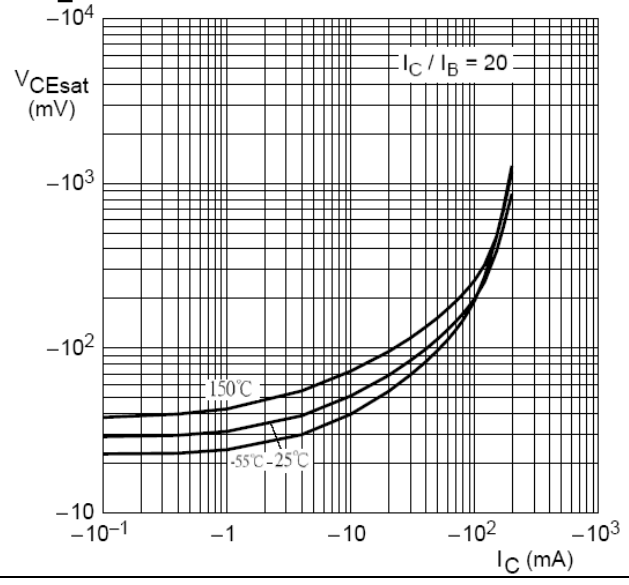
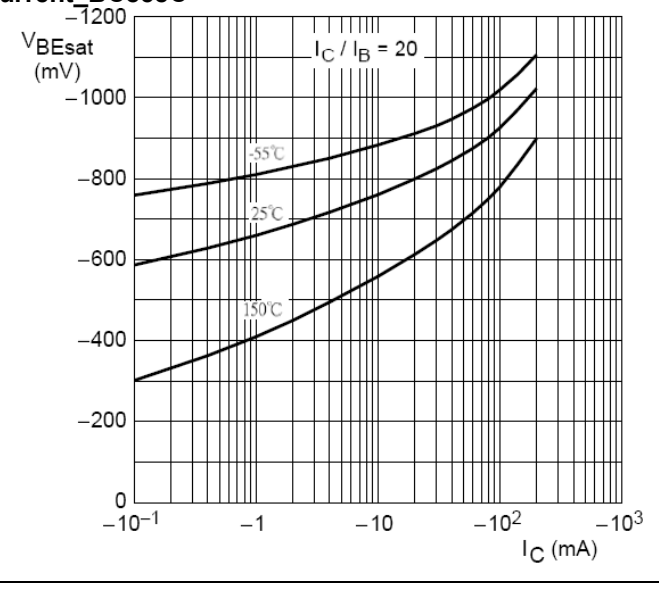


Fig.12 Base Emitter Saturation Voltage vs. Collector Current_BC858C



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